Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- · Very fast switching
- Low threshold voltage
- Trench MOSFET technology
- Side wettable flanks for optical solder inspection
- · Exposed drain pad for excellent thermal conduction

3. Applications

- · Relay driver
- · High-speed line driver
- Low-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	$V_{GS} = 4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	[1]	-	-	14.3	Α
Static charact	eristics		·	·			
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 10.1 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	8.5	12	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



20 V, N-channel Trench MOSFET

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	1 1 1 6	D I
2	D	drain		
3	G	gate	2 5	G (F)
4	S	source	3 8 4	s
5	D	drain	Transparent top view	017aaa253
6	D	drain	DFN2020MD-6 (SOT1220)	
7	D	drain		
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	Package	Package Package							
	Name	Description	Version						
PMPB8XN		DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220						

7. Marking

Table 4. Marking codes

Type number	Marking code
PMPB8XN	5A

20 V, N-channel Trench MOSFET

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V_{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	14.3	А
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	10.1	А
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	6.4	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	40	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	1.9	W
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.8	W
		T _{sp} = 25 °C		-	12.5	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode					
Is	source current	T _{amb} = 25 °C	[1]	-	2	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

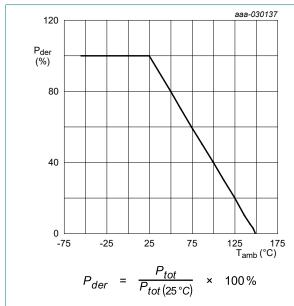


Fig. 1. Normalized total power dissipation as a function of ambient temperature

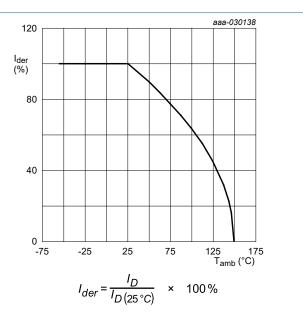


Fig. 2. Normalized continous drain current as a function of ambient temperature

20 V, N-channel Trench MOSFET

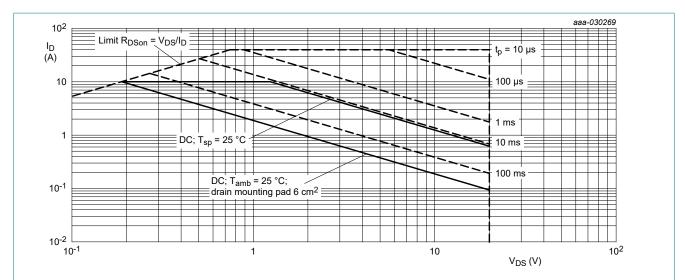


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

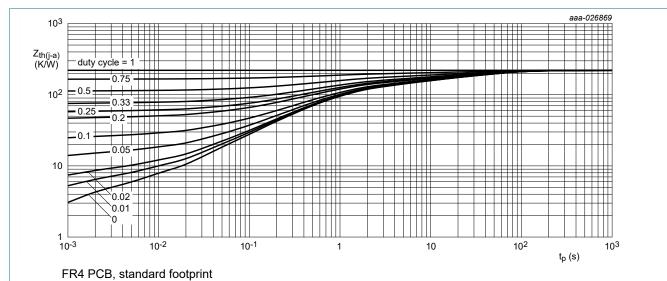
20 V, N-channel Trench MOSFET

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	223	256	K/W
	junction to ambient		[2]	-	57	66	K/W
		in free air; t ≤ 5 s	[2]	-	29	33	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	6	10	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



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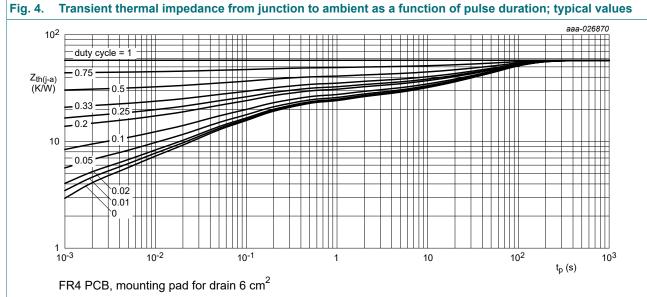


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

20 V, N-channel Trench MOSFET

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.4	0.65	0.9	V
I _{DSS}	drain leakage current	$V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μΑ
I _{GSS}	gate leakage current	V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V _{GS} = 4.5 V; I _D = 10.1 A; T _j = 25 °C	-	8.5	12	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 10.1 A; T _j = 150 °C	-	13	19	mΩ
		$V_{GS} = 2.5 \text{ V}; I_D = 8.7 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	10	16	mΩ
		V _{GS} = 1.8 V; I _D = 3.7 A; T _j = 25 °C	-	16	25	mΩ
		V _{GS} = 1.5 V; I _D = 0.5 A; T _j = 25 °C	-	34	60	mΩ
9fs	forward transconductance	V_{DS} = 10 V; I_D = 5.7 A; T_j = 25 °C	-	24	-	S
R_G	gate resistance	f = 1 MHz	-	2.5	-	Ω
Dynamic ch	naracteristics			'		
Q _{G(tot)}	total gate charge	V _{DS} = 10 V; I _D = 9.5 A; V _{GS} = 4.5 V;	-	20	30	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.7	-	nC
Q _{GD}	gate-drain charge		-	5.9	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; f = 1 MHz; V _{GS} = 0 V;	-	1696	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	224	-	pF
C _{rss}	reverse transfer capacitance		-	195	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 10 V; I _D = 10 A; V _{GS} = 4.5 V;	-	5	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	12	-	ns
$t_{d(off)}$	turn-off delay time	1	-	31	-	ns
t _f	fall time	1	-	15	-	ns
Source-dra	in diode					
	source-drain voltage	I _S = 2 A; V _{GS} = 0 V; T _i = 25 °C		0.7	_	V

20 V, N-channel Trench MOSFET

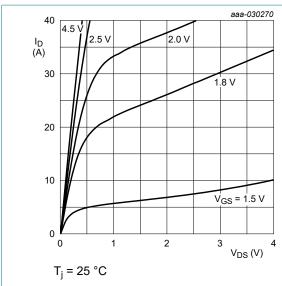


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

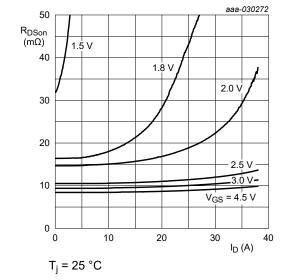


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

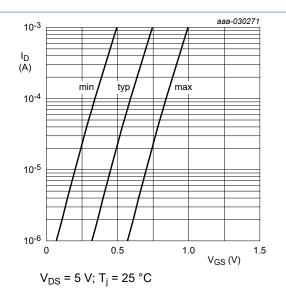


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

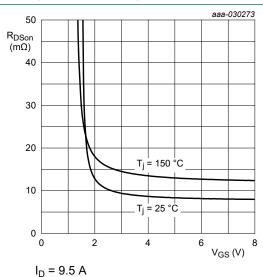


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

20 V, N-channel Trench MOSFET

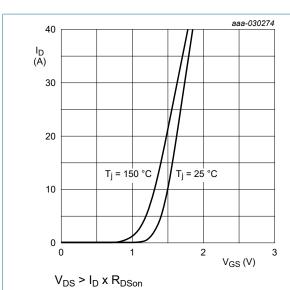


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

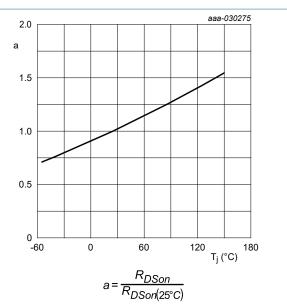


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

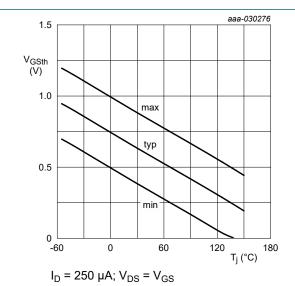


Fig. 12. Gate-source threshold voltage as a function of junction temperature

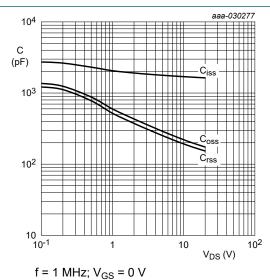


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

20 V, N-channel Trench MOSFET

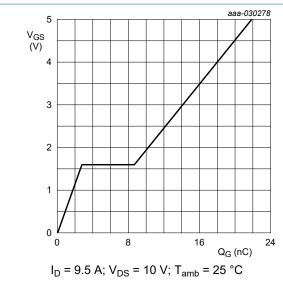


Fig. 14. Gate-source voltage as a function of gate charge; typical values

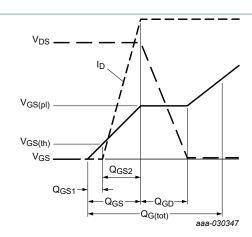


Fig. 15. Gate charge waveform definitions

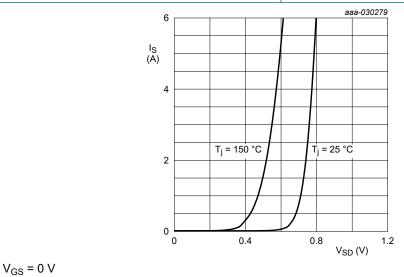
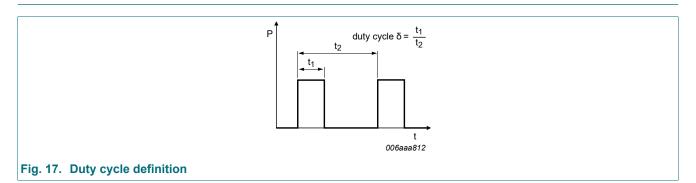


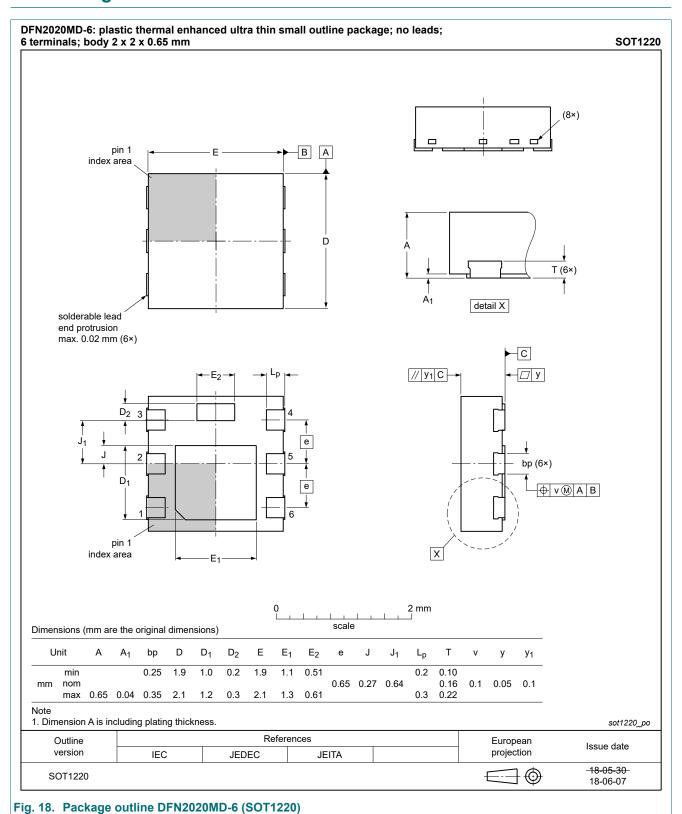
Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information



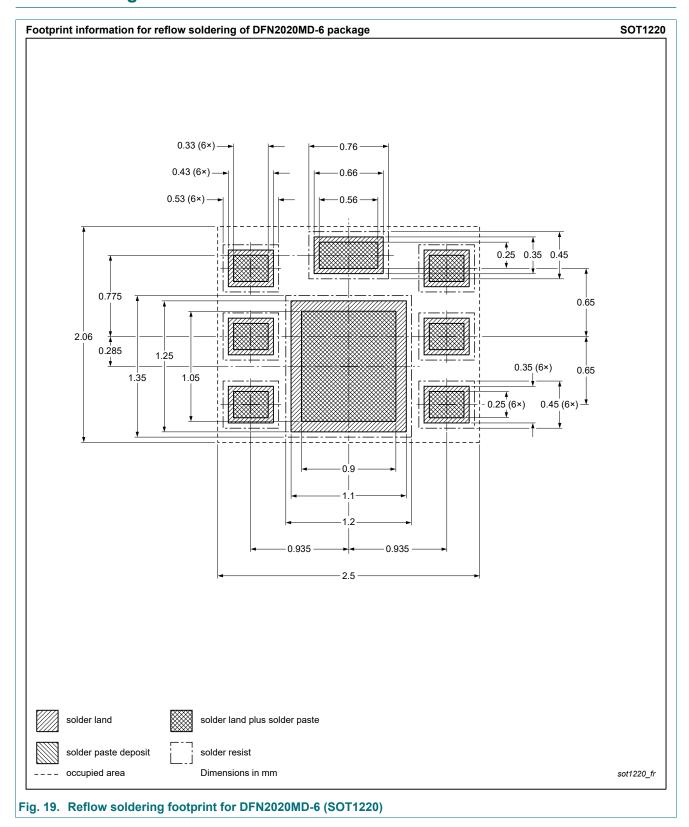
20 V, N-channel Trench MOSFET

12. Package outline



20 V, N-channel Trench MOSFET

13. Soldering



20 V, N-channel Trench MOSFET

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMPB8XN v.1	20190924	Product data sheet	-	-

20 V, N-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Contents

General description	. 1
Features and benefits	. 1
Applications	. 1
Quick reference data	1
Pinning information	2
Ordering information	2
Marking	. 2
Limiting values	. 3
Thermal characteristics	. 5
Characteristics	. 6
Test information	. 9
Package outline	10
Soldering	11
Revision history	12
Legal information	
	Features and benefits

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